

2N3019

NPN medium power transistor

Product specification

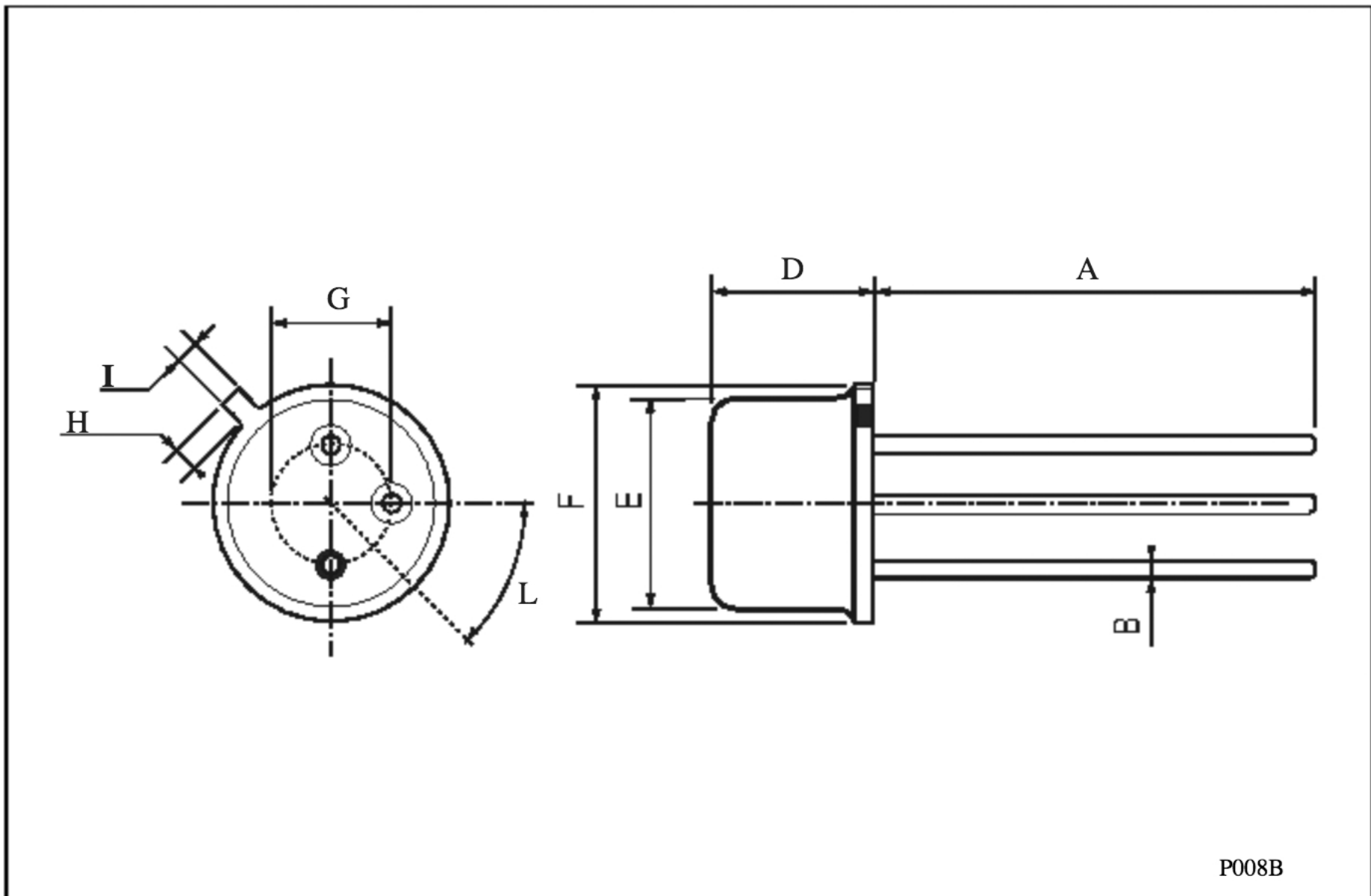
1997 Jun 19

Supersedes data of September 1994

File under Discrete Semiconductors, SC04

TO-39 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	12.7			0.500		
B 0 .	4 9					0.019
D 6 .	6					0.260
E 8 .	5					0.334
F 9 .	4					0.370
G	5.08			0.200		
H 1 .	2					0.047
I 0 .	9					0.035
L	4 5	o (typ.)				



P008B

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